Enpirion® Power Datasheet
EP53A7LQI/EP53A7HQI 1A PowerSoC
Light Load Mode Buck Regulator
with Integrated Inductor

Description
The EP53A7xQI (x = L or H) is a 1000mA PowerSOC. The EP53A7xQI integrates MOSFET switches, control, compensation, and the magnetics in an advanced 3mm x 3mm QFN Package.

Integrated magnetics enables a tiny solution footprint, low output ripple, low part-count, and high reliability, while maintaining high efficiency. The complete solution can be implemented in as little as 21mm².

A proprietary light load mode (LLM) provides high efficiency in light load conditions.

The EP53A7xQI uses a 3-pin VID to easily select the output voltage setting. Output voltage settings are available in 2 optimized ranges providing coverage for typical VOUT settings.

The VID pins can be changed on the fly for fast dynamic voltage scaling. EP53A7LQI further has the option to use an external voltage divider.

The EP53A7xQI offers the optimal combination of very small solution footprint and advanced performance features.

Features
- Integrated Inductor Technology
- 3mm x 3mm x 1.1mm QFN package
- Total Solution Footprint < 21mm²
- Low VOUT ripple for RF compatibility
- High efficiency, up to 94%
- 1000mA continuous output current
- 55μA quiescent current
- Less than 1μA standby current
- 5 MHz switching frequency
- 3 pin VID for glitch free voltage scaling
- VOUT Range 0.6V to VIN – 0.5V
- Short circuit and over current protection
- UVLO and thermal protection
- IC level reliability in a PowerSOC solution

Application
- Portable wireless and RF applications
- Solid state storage applications
- Space constrained applications requiring high efficiency and very small solution size

Figure 1: Total Solution Footprint

Figure 2: Typical Application Schematic

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### Ordering Information

<table>
<thead>
<tr>
<th>Part Number</th>
<th>Comment</th>
<th>Package</th>
</tr>
</thead>
<tbody>
<tr>
<td>EP53A7LQI</td>
<td>LOW VID Range</td>
<td>16-pin QFN T&amp;R</td>
</tr>
<tr>
<td>EP53A7HQI</td>
<td>HIGH VID Range</td>
<td>16-pin QFN T&amp;R</td>
</tr>
</tbody>
</table>

### Pin Assignments (Top View)

**Figure 3: EP53A7LQI Pin Out Diagram (Top View)**

**Figure 4: EP53A7HQI Pin Out Diagram (Top View)**

### Pin Description

<table>
<thead>
<tr>
<th>PIN</th>
<th>NAME</th>
<th>FUNCTION</th>
</tr>
</thead>
<tbody>
<tr>
<td>1, 15, 16</td>
<td>NC(SW)</td>
<td>NO CONNECT – These pins are internally connected to the common switching node of the internal MOSFETs. NC (SW) pins are not to be electrically connected to any external signal, ground, or voltage. However, they must be soldered to the PCB. Failure to follow this guideline may result in part malfunction or damage to the device.</td>
</tr>
<tr>
<td>2</td>
<td>PGND</td>
<td>Power ground. Connect this pin to the ground electrode of the input and output filter capacitors.</td>
</tr>
<tr>
<td>3</td>
<td>LLM</td>
<td>LLM (Light load mode – “LLM”) pin. Logic-High enables automatic LLM/PWM and logic-low places the device in fixed PWM operation.</td>
</tr>
<tr>
<td>5</td>
<td>VSENSE</td>
<td>Sense pin for preset output voltages. Refer to application section for proper configuration.</td>
</tr>
<tr>
<td>6</td>
<td>AGND</td>
<td>Analog ground. This is the quiet ground for the internal control circuitry, and the ground return for external feedback voltage divider</td>
</tr>
<tr>
<td>7, 8</td>
<td>VOUT</td>
<td>Regulated Output Voltage. Refer to application section for proper layout and decoupling.</td>
</tr>
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</table>
### PIN NAME FUNCTION

<table>
<thead>
<tr>
<th>PIN</th>
<th>NAME</th>
<th>FUNCTION</th>
</tr>
</thead>
<tbody>
<tr>
<td>9, 10, 11</td>
<td>VS2, VS1, VS0</td>
<td>Output voltage select. VS2 = pin 9, VS1 = pin 10, VS0 = pin 11. EP53A7LQI: Selects one of seven preset output voltages or an external resistor divider. EP53A7HQI: Selects one of eight preset output voltages. (Refer to section on output voltage select for more details.)</td>
</tr>
<tr>
<td>12</td>
<td>ENABLE</td>
<td>Output Enable. Enable = logic high; Disable = logic low</td>
</tr>
<tr>
<td>13</td>
<td>AVIN</td>
<td>Input power supply for the controller circuitry. Connect to PVIN through a 100 Ohm resistor.</td>
</tr>
<tr>
<td>14</td>
<td>PVIN</td>
<td>Input Voltage for the MOSFET switches.</td>
</tr>
</tbody>
</table>

### Absolute Maximum Ratings

CAUTION: Absolute Maximum ratings are stress ratings only. Functional operation beyond the recommended operating conditions is not implied. Stress beyond the absolute maximum ratings may cause permanent damage to the device. Exposure to absolute maximum rated conditions for extended periods may affect device reliability.

<table>
<thead>
<tr>
<th>PARAMETER</th>
<th>SYMBOL</th>
<th>MIN</th>
<th>MAX</th>
<th>UNITS</th>
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<tr>
<td>Input Supply Voltage</td>
<td>$V_{IN}$</td>
<td>-0.3</td>
<td>6.0</td>
<td>V</td>
</tr>
<tr>
<td>Voltages on: ENABLE, $V_{SENSE}$, $V_{SO} - V_{S2}$</td>
<td>-0.3</td>
<td>$V_{IN} + 0.3$</td>
<td>V</td>
<td></td>
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<tr>
<td>Voltages on: $V_{FB}$ (EP53A7LQI)</td>
<td>-0.3</td>
<td>2.7</td>
<td>V</td>
<td></td>
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<tr>
<td>Maximum Operating Junction Temperature</td>
<td>$T_{JA}$</td>
<td>150</td>
<td>°C</td>
<td></td>
</tr>
<tr>
<td>Storage Temperature Range</td>
<td>$T_{STG}$</td>
<td>-65</td>
<td>150</td>
<td>°C</td>
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<tr>
<td>Reflow Temp, 10 Sec, MSL3 JEDEC J-STD-020C</td>
<td></td>
<td></td>
<td>260</td>
<td>°C</td>
</tr>
<tr>
<td>ESD Rating (based on Human Body Mode)</td>
<td></td>
<td></td>
<td>2000</td>
<td>V</td>
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### Recommended Operating Conditions

<table>
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<tr>
<th>PARAMETER</th>
<th>SYMBOL</th>
<th>MIN</th>
<th>MAX</th>
<th>UNITS</th>
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</thead>
<tbody>
<tr>
<td>Input Voltage Range</td>
<td>$V_{IN}$</td>
<td>2.4</td>
<td>5.5</td>
<td>V</td>
</tr>
<tr>
<td>Operating Ambient Temperature</td>
<td>$T_{A}$</td>
<td>-40</td>
<td>+85</td>
<td>°C</td>
</tr>
<tr>
<td>Operating Junction Temperature</td>
<td>$T_{J}$</td>
<td>-40</td>
<td>+125</td>
<td>°C</td>
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### Thermal Characteristics

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<th>TYP</th>
<th>UNITS</th>
</tr>
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<tbody>
<tr>
<td>Thermal Resistance: Junction to Ambient –0 LFM (Note 1)</td>
<td>$\theta_{JA}$</td>
<td>80</td>
<td>°C/W</td>
</tr>
<tr>
<td>Thermal Overload Trip Point</td>
<td>$T_{J-TP}$</td>
<td>+155</td>
<td>°C</td>
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<tr>
<td>Thermal Overload Trip Point Hysteresis</td>
<td></td>
<td>25</td>
<td>°C</td>
</tr>
</tbody>
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**Note 1:** Based on a four layer copper board and proper thermal design per JEDEC EIJ/JESD51 standards
## Electrical Characteristics

NOTE: $T_A = -40^\circ C$ to $+85^\circ C$ unless otherwise noted. Typical values are at $T_A = 25^\circ C$, $V_{IN} = 3.6V$, $C_{IN} = -4.7\mu F$ MLCC, $C_{OUT} = 10\mu F$ MLCC.

<table>
<thead>
<tr>
<th>PARAMETER</th>
<th>SYMBOL</th>
<th>TEST CONDITIONS</th>
<th>MIN</th>
<th>TYP</th>
<th>MAX</th>
<th>UNITS</th>
</tr>
</thead>
<tbody>
<tr>
<td>Operating Input Voltage</td>
<td>$V_{IN}$</td>
<td></td>
<td>2.4</td>
<td>5.5</td>
<td></td>
<td>V</td>
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<tr>
<td>Under Voltage Lock-out – $V_{IN}$ Rising</td>
<td>$V_{UVLO_R}$</td>
<td></td>
<td></td>
<td></td>
<td>2.0</td>
<td>V</td>
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<tr>
<td>Under Voltage Lock-out – $V_{IN}$ Falling</td>
<td>$V_{UVLO_F}$</td>
<td></td>
<td></td>
<td></td>
<td>1.9</td>
<td>V</td>
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<tr>
<td>Drop Out Resistance</td>
<td>$R_{DO}$</td>
<td>Input to Output Resistance</td>
<td></td>
<td></td>
<td>350</td>
<td>500</td>
</tr>
<tr>
<td>Output Voltage Range</td>
<td>$V_{OUT}$</td>
<td>EP53A7LQI ($V_{DO} = I_{LOAD} \times R_{DO}$) EP53A7HQI</td>
<td>0.6</td>
<td>1.8</td>
<td></td>
<td>V</td>
</tr>
<tr>
<td>Dynamic Voltage Slew Rate</td>
<td>$V_{SLEW}$</td>
<td>EP53A7LQI EP53A7HQI</td>
<td></td>
<td></td>
<td>4</td>
<td>8</td>
</tr>
<tr>
<td>VID Preset $V_{OUT}$ Initial Accuracy</td>
<td>$\Delta V_{OUT}$</td>
<td>$T_A = 25^\circ C$, $V_{IN} = 3.6V$; $I_{LOAD} = 100mA$; $0.8V \leq V_{OUT} \leq 3.3V$</td>
<td>-2</td>
<td></td>
<td>+2</td>
<td>%</td>
</tr>
<tr>
<td>Feedback Pin Voltage Initial Accuracy</td>
<td>$V_{FB}$</td>
<td>$T_A = 25^\circ C$, $V_{IN} = 3.6V$; $I_{LOAD} = 100mA$; $0.8V \leq V_{OUT} \leq 3.3V$</td>
<td></td>
<td></td>
<td>0.588</td>
<td>0.6</td>
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<tr>
<td>Line Regulation</td>
<td>$\Delta V_{OUT_LINE}$</td>
<td>2.4V $\leq V_{IN} \leq 5.5V$</td>
<td></td>
<td></td>
<td>0.03</td>
<td></td>
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<tr>
<td>Load Regulation</td>
<td>$\Delta V_{OUT_LOAD}$</td>
<td>0A $\leq I_{LOAD} \leq 1000mA$</td>
<td></td>
<td></td>
<td></td>
<td>0.6</td>
</tr>
<tr>
<td>Temperature Variation</td>
<td>$\Delta V_{OUT_TEMPL}$</td>
<td>$-40^\circ C \leq T_A \leq +85^\circ C$</td>
<td></td>
<td></td>
<td>30</td>
<td></td>
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<tr>
<td>Output Current</td>
<td>$I_{OUT}$</td>
<td></td>
<td></td>
<td></td>
<td>1000</td>
<td></td>
</tr>
<tr>
<td>Shut-down Current</td>
<td>$I_{SD}$</td>
<td>Enable = Low</td>
<td></td>
<td></td>
<td>0.75</td>
<td></td>
</tr>
<tr>
<td>EP53A7LQI Operating Quiescent Current</td>
<td>$I_Q$</td>
<td>$I_{LOAD}=0$; Preset Output Voltages, LLM=High</td>
<td></td>
<td></td>
<td>55</td>
<td></td>
</tr>
<tr>
<td>EP53A7HQI Operating Quiescent Current</td>
<td>$I_Q$</td>
<td>$I_{LOAD}=0$; Preset Output Voltages, LLM=High</td>
<td></td>
<td></td>
<td>65</td>
<td></td>
</tr>
<tr>
<td>OCP Threshold</td>
<td>$I_{LIM}$</td>
<td>2.4V $\leq V_{IN} \leq 5.5V$ 0.6V $\leq V_{OUT} \leq 3.3V$</td>
<td></td>
<td></td>
<td>1.25</td>
<td>1.4</td>
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<tr>
<td>Feedback Pin Input Current</td>
<td>$I_{FB}$</td>
<td>Note 1</td>
<td></td>
<td></td>
<td>&lt;100</td>
<td></td>
</tr>
<tr>
<td>VS0-VS2, Pin Logic Low</td>
<td>$V_{VSLO}$</td>
<td></td>
<td></td>
<td></td>
<td>0.0</td>
<td>0.3</td>
</tr>
<tr>
<td>VS0-VS2, Pin Logic High</td>
<td>$V_{VSHI}$</td>
<td></td>
<td></td>
<td></td>
<td>1.4</td>
<td></td>
</tr>
<tr>
<td>VS0-VS2, Pin Input Current</td>
<td>$I_{VSX}$</td>
<td>Note 1</td>
<td></td>
<td></td>
<td>&lt;100</td>
<td></td>
</tr>
<tr>
<td>Enable Pin Logic Low</td>
<td>$V_{ENLO}$</td>
<td></td>
<td></td>
<td></td>
<td>0.3</td>
<td></td>
</tr>
<tr>
<td>Enable Pin Logic High</td>
<td>$V_{ENHI}$</td>
<td></td>
<td></td>
<td></td>
<td>1.4</td>
<td></td>
</tr>
<tr>
<td>Enable Pin Current</td>
<td>$I_{ENABLE}$</td>
<td>Note 1</td>
<td></td>
<td></td>
<td>&lt;100</td>
<td></td>
</tr>
<tr>
<td>LLM Engage Headroom</td>
<td>Minimum difference between $V_{IN}$ and $V_{OUT}$ to ensure proper LLM operation</td>
<td></td>
<td></td>
<td></td>
<td>700</td>
<td></td>
</tr>
<tr>
<td>LLM Pin Logic Low</td>
<td>$V_{LLMLO}$</td>
<td></td>
<td></td>
<td></td>
<td>0.3</td>
<td></td>
</tr>
<tr>
<td>LLM Pin Logic High</td>
<td>$V_{LLMHI}$</td>
<td></td>
<td></td>
<td></td>
<td>1.4</td>
<td></td>
</tr>
</tbody>
</table>

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<table>
<thead>
<tr>
<th>PARAMETER</th>
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<th>TEST CONDITIONS</th>
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<th>TYP</th>
<th>MAX</th>
<th>UNITS</th>
</tr>
</thead>
<tbody>
<tr>
<td>LLM Pin Current</td>
<td>$I_{LLM}$</td>
<td></td>
<td>&lt;100</td>
<td></td>
<td></td>
<td>nA</td>
</tr>
<tr>
<td>Operating Frequency</td>
<td>$F_{OSC}$</td>
<td></td>
<td>5</td>
<td></td>
<td></td>
<td>MHz</td>
</tr>
</tbody>
</table>

### Soft Start Operation

| Soft Start Slew Rate    | $\Delta V_{SS}$ | EP53A7LQI (VID only) | 4   | 8   |     | V/mS  |
| Soft Start Rise Time    | $\Delta T_{SS}$ | EP53A7LQI (VFB mode); Note 2 | 170 | 225 | 280 | $\mu$S |

**Note 1:** Parameter guaranteed by design  
**Note 2:** Measured from when $V_{IN} \geq V_{UVLO\_R}$ & ENABLE pin crosses its logic High threshold.

### Typical Performance Characteristics

- **Efficiency vs. Load Current:** $V_{OUT} = 1.2\,V$, $V_{IN}$ (from top to bottom) = 2.5, 3.3, 3.7, 4.3, 5.0\,V
- **Efficiency vs. Load Current:** $V_{OUT} = 1.8\,V$, $V_{IN}$ (from top to bottom) = 2.5, 3.3, 3.7, 4.3, 5.0\,V
- **Efficiency vs. Load Current:** $V_{OUT} = 2.5\,V$, $V_{IN}$ (from top to bottom) = 3.3, 3.7, 4.3, 5.0\,V
- **Efficiency vs. Load Current:** $V_{OUT} = 3.3\,V$, $V_{IN}$ (from top to bottom) = 3.7, 4.3, 5.0\,V
Start Up Waveform: $V_{IN} = 5.0V$, $V_{OUT} = 3.3V$; $I_{LOAD} = 10mA$; VID Mode

Start Up Waveform: $V_{IN} = 5.0V$, $V_{OUT} = 3.3V$; $I_{LOAD} = 1000mA$; VID Mode

Shut-down Waveform: $V_{IN} = 5.0V$, $V_{OUT} = 3.3V$; $I_{LOAD} = 10mA$, PWM

Shut-down Waveform: $V_{IN} = 5.0V$, $V_{OUT} = 3.3V$; $I_{LOAD} = 1000mA$, PWM

Output Ripple: $V_{IN} = 5.0V$, $V_{OUT} = 1.2V$, Load = 10mA
LLM enabled

Output Ripple: $V_{IN} = 5.0V$, $V_{OUT} = 1.2V$, Load = 1A
50mV/Div

5mV/Div
Output Ripple: \( V_{IN} = 5.0V, \ V_{OUT} = 3.3V, \ \text{Load} = 10mA \)  
LLM enabled

Output Ripple: \( V_{IN} = 3.3V, \ V_{OUT} = 1.8V, \ \text{Load} = 10mA \)  
LLM enabled

Output Ripple: \( V_{IN} = 3.3V, \ V_{OUT} = 1.2V, \ \text{Load} = 10mA \)  
LLM enabled

Output Ripple: \( V_{IN} = 5.0V, \ V_{OUT} = 3.3V, \ \text{Load} = 1A \)

Output Ripple: \( V_{IN} = 3.3V, \ V_{OUT} = 1.8V, \ \text{Load} = 1A \)

Output Ripple: \( V_{IN} = 3.3V, \ V_{OUT} = 1.2V, \ \text{Load} = 1A \)
Load Transient: \( V_{\text{IN}} = 5.0\,\text{V}, \, V_{\text{OUT}} = 3.3\,\text{V} \)
Load stepped from 0mA to 1000mA

Load Transient: \( V_{\text{IN}} = 5.0\,\text{V}, \, V_{\text{OUT}} = 3.3\,\text{V} \)
Load stepped from 10mA to 1000mA, LLM enabled

Load Transient: \( V_{\text{IN}} = 5.0\,\text{V}, \, V_{\text{OUT}} = 1.2\,\text{V} \)
Load stepped from 0mA to 1000mA

Load Transient: \( V_{\text{IN}} = 5.0\,\text{V}, \, V_{\text{OUT}} = 1.2\,\text{V} \)
Load stepped from 10mA to 1000mA, LLM enabled
Load Transient: $V_{IN} = 3.7V$, $V_{OUT} = 1.2V$
Load stepped from 0mA to 1000mA

Load Transient: $V_{IN} = 3.7V$, $V_{OUT} = 1.2V$
Load stepped from 10mA to 1000mA, LLM enabled

Load Transient: $V_{IN} = 3.3V$, $V_{OUT} = 1.8V$
Load stepped from 0mA to 1000mA

Load Transient: $V_{IN} = 3.3V$, $V_{OUT} = 1.8V$
Load stepped from 10mA to 1000mA, LLM enabled
Figure 5: Functional Block Diagram
Detailed Description

Functional Overview

The EP53A7xQI requires only 2 small MLCC capacitors and an 0201 resistor for a complete DC-DC converter solution. The device integrates MOSFET switches, PWM controller, Gate-drive, compensation, and inductor into a tiny 3mm x 3mm x 1.1mm QFN package. Advanced package design, along with the high level of integration, provides very low output ripple and noise. The EP53A7xQI uses voltage mode control for high noise immunity and load matching to advanced ≤90nm loads. A 3-pin VID allows the user to choose from one of 8 output voltage settings. The EP53A7xQI comes with two VID output voltage ranges. The EP53A7HQI provides VOUT settings from 1.8V to 3.3V, the EP53A7LQI provides VID settings from 0.8V to 1.5V, and also has an external resistor divider option to program output setting over the 0.6V to VIN-0.5V range. The EP53A7xQI provides the industry's highest power density of any 1A DCDC converter solution.

The key enabler of this revolutionary integration is Altera Enpirion’s proprietary power MOSFET technology. The advanced MOSFET switches are implemented in deep-submicron CMOS to supply very low switching loss at high switching frequencies and to allow a high level of integration. The semiconductor process allows seamless integration of all switching, control, and compensation circuitry.

The proprietary magentics design provides high-density/high-value magnetics in a very small footprint. Altera Enpirion magnetics are carefully matched to the control and compensation circuitry yielding an optimal solution with assured performance over the entire operating range.

Protection features include under-voltage lockout (UVLO), over-current protection (OCP), short circuit protection, and thermal overload protection.

Integrated Inductor

The EP53A7xQI utilizes a proprietary low loss integrated inductor. The integration of the inductor greatly simplifies the power supply design process. The integrated inductor provides the optimal solution to the complexity, output ripple, and noise that plague low power DCDC converter design.

Voltage Mode Control

The EP53A7xQI utilizes an integrated type III compensation network. Voltage mode control is inherently impedance matched to the sub 90nm process technology that is used in today’s advanced ICs. Voltage mode control also provides a high degree of noise immunity at light load currents so that low ripple and high accuracy are maintained over the entire load range. The very high switching frequency allows for a very wide control loop bandwidth and hence excellent transient performance.

Light Load Mode (LLM) Operation

The EP53A7xQI uses a proprietary light load mode to provide high efficiency in the low load operating condition. When the LLM pin is high, the device is in automatic LLM/PWM mode. When the LLM pin is low, the device is in PWM mode. In automatic LLM/PWM mode, when a light load condition is detected, the device will (1) step VOUT up by approximately 1.5% above the nominal operating output voltage setting, VNOM, and then (2) shut down unnecessary circuitry, and (3) monitor VOUT. When VOUT falls below VNOM, the device will repeat (1), (2), and (3). The voltage step up, or pre-positioning, improves transient droop when a load transient causes a transition from LLM mode to PWM mode. If a load transient occurs, causing VOUT to fall below the threshold VMIN, the device will exit LLM operation and begin normal PWM operation. Figure 6 demonstrates VOUT behavior during transition into and out of LLM operation.
Many multi-mode DCDC converters suffer from a condition that occurs when the load current increases only slowly so that there is no load transient driving VOUT below the V_MIN threshold (shown in Figure 6). In this condition, the device would never exit LLM operation. This could adversely affect efficiency and cause unwanted ripple. To prevent this from occurring, the EP53A7xQI periodically exits LLM mode into PWM mode and measures the load current. If the load current is above the LLM threshold current, the device will remain in PWM mode. If the load current is below the LLM threshold, the device will re-enter LLM operation. There will be a small droop in VOUT at the point where the device exits and re-enters LLM, as shown in Figure 7.

The load current at which the device will enter LLM mode is a function of input and output voltage. Figure 8 shows the typical value at which the device will enter LLM operation. The actual load current at which the device will enter LLM operation can vary by +/-30%. Table 1 shows the minimum load current below which the device is guaranteed to be in LLM operating mode.

To ensure normal LLM operation, LLM mode should be enabled/disabled with specific sequencing. For applications with explicit LLM pin control, enable LLM after VIN ramp up complete; disable LLM before VIN ramp down. For applications with ENABLE control, tie LLM to ENABLE; enable device after VIN ramp up complete and disable device before VIN ramp down.
down begins. For devices with ENABLE and LLM tied to VIN, contact Altera Applications engineering for specific recommendations.

Increased output filter capacitance and/or increased bulk capacitance at the load will decrease the magnitude of the LLM ripple. Refer to the section on output filter capacitance for maximum values of output filter capacitance and the Soft-Start section for maximum bulk capacitance at the load.

**NOTE:** For proper LLM operation the EP53A7xQI requires a minimum difference between \(V_{IN}\) and \(V_{OUT}\) of 700mV. If this condition is not met, the device cannot be assured proper LLM operation.

**NOTE:** Automatic LLM/PWM is not available when using the external resistor divider option for \(V_{OUT}\) programming.

**Soft Start**

Internal soft start circuits limit in-rush current when the device starts up from a power down condition or when the “ENABLE” pin is asserted “high”. Digital control circuitry limits the \(V_{OUT}\) ramp rate to levels that are safe for the Power MOSFETS and the integrated inductor.

The EP53A7HQI has a soft-start slew rate that is twice that of the EP53A7LQI.

When the EP53A7LUI is configured in external resistor divider mode, the device has a fixed \(V_{OUT}\) ramp time. Therefore, the ramp rate will vary with the output voltage setting. Output voltage ramp time is given in the Electrical Characteristics Table.

Excess bulk capacitance on the output of the device can cause an over-current condition at startup. The maximum total capacitance on the output, including the output filter capacitor and bulk and decoupling capacitance, at the load, is given as:

**EP53A7LQI:**
\[
C_{OUT\_TOTAL\_MAX} = C_{OUT\_Filter} + C_{OUT\_BULK} = 200uF
\]

**EP53A7HQI:**
\[
C_{OUT\_TOTAL\_MAX} = C_{OUT\_Filter} + C_{OUT\_BULK} = 100uF
\]

**EP53A7LUI** in external divider mode:
\[
C_{OUT\_TOTAL\_MAX} = 2.25 \times 10^{-4} / V_{OUT} \text{ Farads}
\]

The nominal value for \(C_{OUT}\) is 10uF. See the applications section for more details.

**Over Current/Short Circuit Protection**

The current limit function is achieved by sensing the current flowing through a sense P-MOSFET which is compared to a reference current. When this level is exceeded the P-FET is turned off and the N-FET is turned on, pulling \(V_{OUT}\) low. This condition is maintained for approximately 0.5mS and then a normal soft start is initiated. If the over current condition still persists, this cycle will repeat.

**Under Voltage Lockout**

During initial power up, an under voltage lockout circuit will hold-off the switching circuitry until the input voltage reaches a sufficient level to insure proper operation. If the voltage drops below the UVLO threshold, the lockout circuitry will again disable the switching. Hysteresis is included to prevent chattering between states.

**Enable**

The ENABLE pin provides a means to shut down the converter or enable normal operation. A logic low will disable the converter and cause it to shut down. A logic high will enable the converter into normal operation.

**NOTE:** The ENABLE pin must not be left floating.

**Thermal Shutdown**

When excessive power is dissipated in the chip, the junction temperature rises. Once the junction temperature exceeds the thermal shutdown temperature, the thermal shutdown circuit turns off the converter output voltage thus allowing the device to cool. When the junction temperature decreases by 25°C, the device will go through the normal startup process.
**Application Information**

![Application Circuit, EP53A7HQI](image)

**Figure 9:** Application Circuit, EP53A7HQI. Note that all control signals should be connected to an external control signal, AVIN or AGND.

![Application Circuit, EP53A7LQI showing the VFB function.](image)

**Figure 10:** Application Circuit, EP53A7LQI showing the VFB function.

**Output Voltage Programming**

The EP53A7xQI utilizes a 3-pin VID to program the output voltage value. The VID is available in two sets of output VID programming ranges. The VID pins should be connected either to an external control signal, AVIN or to AGND to avoid noise coupling into the device. The VID pins must not be left floating.

The “Low” range is optimized for low voltage applications. It comes with preset VID settings ranging from 0.80V and 1.5V. This VID set also has an external divider option.

To specify this VID range, order part number EP53A7LQI.

The “High” VID set provides output voltage settings ranging from 1.8V to 3.3V. This version does not have an external divider option. To specify this VID range, order part number EP53A7HQI.

Internally, the output of the VID multiplexer sets the value for the voltage reference DAC, which in turn is connected to the non-inverting input of the error amplifier. This allows the use of a single feedback divider with constant loop gain and optimum compensation, independent of the output voltage selected.

**NOTE:** The VID pins must not be left floating.

**EP53A7L Low VID Range Programming**

The EP53A7LQI is designed to provide a high degree of flexibility in powering applications that require low VOUT settings and dynamic voltage scaling (DVS). The device employs a 3-pin VID architecture that allows the user to choose one of seven (7) preset output voltage settings, or the user can select an external voltage divider option. The VID pin settings can be changed on the fly to implement glitch-free voltage scaling.

<table>
<thead>
<tr>
<th>VS2</th>
<th>VS1</th>
<th>VS0</th>
<th>VOUT</th>
</tr>
</thead>
<tbody>
<tr>
<td>0</td>
<td>0</td>
<td>0</td>
<td>1.50</td>
</tr>
<tr>
<td>0</td>
<td>0</td>
<td>1</td>
<td>1.45</td>
</tr>
<tr>
<td>0</td>
<td>1</td>
<td>0</td>
<td>1.20</td>
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<tr>
<td>0</td>
<td>1</td>
<td>1</td>
<td>1.15</td>
</tr>
<tr>
<td>1</td>
<td>0</td>
<td>0</td>
<td>1.10</td>
</tr>
<tr>
<td>1</td>
<td>0</td>
<td>1</td>
<td>1.05</td>
</tr>
<tr>
<td>1</td>
<td>1</td>
<td>0</td>
<td>0.8</td>
</tr>
<tr>
<td>1</td>
<td>1</td>
<td>1</td>
<td>EXT</td>
</tr>
</tbody>
</table>

Table 2 shows the VS2-VS0 pin logic states for the EP53A7LQI and the associated output voltage levels. A logic “1” indicates a connection to AVIN or to a “high” logic voltage level. A logic “0” indicates a connection to AGND or to a “low” logic voltage level. These pins can be either hardwired to AVIN or AGND or alternatively can be driven by standard logic levels. Logic levels are defined in the electrical characteristics table. Any level between the logic high and logic low is indeterminate.

**EP53A7LQI External Voltage Divider**

The external divider option is chosen by connecting VID pins VS2-VS0 to AVIN or a logic “1" or "high”. The EP53A7LQI uses a separate feedback pin, VFB, when using the external divider. VSENSE must be connected to VOUT as indicated in Figure 11.
The output voltage is selected by the following formula:

\[ V_{OUT} = 0.6V \left( 1 + \frac{R_b}{R_a} \right) \]

\( R_a \) must be chosen as 237KΩ to maintain loop gain. Then \( R_b \) is given as:

\[ R_b = \frac{142.2 \times 10^3}{V_{OUT} - 0.6} \Omega \]

\( V_{OUT} \) can be programmed over the range of 0.6V to \((V_{IN} - 0.5V)\).

**NOTE:** Dynamic Voltage Scaling is not allowed between internal preset voltages and external divider.

**NOTE:** LLM is not functional when using the external divider option. Tie the LLM pin to AGND when using this option.

### EP53A7HQI High VID Range Programming

The EP53A7HQI \( V_{OUT} \) settings are optimized for higher nominal voltages such as those required to power IO, RF, or IC memory. The preset voltages range from 1.8V to 3.3V. There are eight (8) preset output voltage settings. The EP53A7HQI does not have an external divider option. As with the EP53A7LQI, the VID pin settings can be changed while the device is enabled.

Table 3 shows the VS0-VS2 pin logic states for the EP53A7HQI and the associated output voltage levels. A logic “1” indicates a connection to AVIN or to a “high” logic voltage level. A logic “0” indicates a connection to AGND or to a “low” logic voltage level. These pins can be either hardwired to AVIN or AGND or alternatively can be driven by standard logic levels. Logic levels are defined in the electrical characteristics table. Any level between the logic high and logic low is indeterminate. These pins must not be left floating.

**Table 3: EP53A7HQI VID Voltage Select Settings**

<table>
<thead>
<tr>
<th>VS2</th>
<th>VS1</th>
<th>VS0</th>
<th>VOUT</th>
</tr>
</thead>
<tbody>
<tr>
<td>0</td>
<td>0</td>
<td>0</td>
<td>3.3</td>
</tr>
<tr>
<td>0</td>
<td>0</td>
<td>1</td>
<td>3.0</td>
</tr>
<tr>
<td>0</td>
<td>1</td>
<td>0</td>
<td>2.9</td>
</tr>
<tr>
<td>0</td>
<td>1</td>
<td>1</td>
<td>2.6</td>
</tr>
<tr>
<td>1</td>
<td>0</td>
<td>0</td>
<td>2.5</td>
</tr>
<tr>
<td>1</td>
<td>0</td>
<td>1</td>
<td>2.2</td>
</tr>
<tr>
<td>1</td>
<td>1</td>
<td>0</td>
<td>2.1</td>
</tr>
<tr>
<td>1</td>
<td>1</td>
<td>1</td>
<td>1.8</td>
</tr>
</tbody>
</table>

### Power-Up/Down Sequencing

During power-up, ENABLE should not be asserted before PVIN, and PVIN should not be asserted before AVIN. The PVIN should never be powered when AVIN is off. During power down, the AVIN should not be powered down before the PVIN. Tying PVIN and AVIN or all three pins (AVIN, PVIN, ENABLE) together during power up or power down meets these requirements.

### Pre-Bias Start-up

The EP53A7xQI does not support startup into a pre-biased condition. Be sure the output capacitors are not charged or the output of the EP53A7xQI is not pre-biased when the EP53A7xQI is first enabled.

### Input Filter Capacitor

The input filter capacitor requirement is a 4.7µF 0402 or 0603 low ESR MLCC capacitor.

### Output Filter Capacitor

The output filter capacitor requirement is a minimum of 10µF 0805 MLCC. Ripple performance can be improved by using 2x10µF 0603 or 2x10µF 0805 MLCC capacitors.

The maximum output filter capacitance next to the output pins of the device is 60µF low ESR MLCC capacitance. \( V_{OUT} \) has to be sensed at the last output filter capacitor next to the EP53A7xQI.

Additional bulk capacitance for decoupling and
bypass can be placed at the load as long as there is sufficient separation between the $V_{OUT}$ Sense point and the bulk capacitance. The separation provides an inductance that isolates the control loop from the bulk capacitance.

**NOTE:** Excess total capacitance on the output (Output Filter + Bulk) can cause an overcurrent condition at startup. Refer to the section on Soft-Start for the maximum total capacitance on the output.

**NOTE:** The Input and Output capacitors must use a X5R or X7R or equivalent dielectric formulation. Y5V or equivalent dielectric formulations lose capacitance with frequency, bias, and temperature and are not suitable for switch-mode DC-DC converter filter applications.
**Layout Recommendation**

Figure 12 shows critical components and layer 1 traces of a recommended minimum footprint EP53A7LQI/EP53A7HQI layout with ENABLE tied to \( V_{IN} \). Alternate ENABLE configurations, and other small signal pins need to be connected and routed according to specific customer application. Please see the Gerber files on the Altera website [www.altera.com/enpirion](http://www.altera.com/enpirion) for exact dimensions and other layers. Please refer to Figure 12 while reading the layout recommendations in this section.

**Recommendation 1:** Input and output filter capacitors should be placed on the same side of the PCB, and as close to the EP53A7QI package as possible. They should be connected to the device with very short and wide traces. Do not use thermal reliefs or spokes when connecting the capacitor pads to the respective nodes. The +V and GND traces between the capacitors and the EP53A7QI should be as close to each other as possible so that the gap between the two nodes is minimized, even under the capacitors.

**Recommendation 2:** Input and output grounds are separated until they connect at the PGND pins. The separation shown on Figure 12 between the input and output GND circuits helps minimize noise coupling between the converter input and output switching loops.

**Recommendation 3:** The system ground plane should be the first layer immediately below the surface layer. This ground plane should be continuous and un-interrupted below the converter and the input/output capacitors. Please see the Gerber files on the Altera website [www.altera.com/enpirion](http://www.altera.com/enpirion).

**Recommendation 4:** Multiple small vias should be used to connect the ground traces under the device to the system ground plane on another layer for heat dissipation. The drill diameter of the vias should be 0.33mm, and the vias must have at least 1 oz. copper plating on the inside wall, making the finished hole size around 0.20-0.26mm. Do not use thermal reliefs or spokes to connect the vias to the ground plane. It is preferred to put these vias under the capacitors along the edge of the GND copper closest to the +V copper. Please see Figure 12. These vias connect the input/output filter capacitors to the GND plane and help reduce parasitic inductances in the input and output current loops. If the vias cannot be placed under \( C_{IN} \) and \( C_{OUT} \), then put them just outside the capacitors along the GND. Do not use thermal reliefs or spokes to connect these vias to the ground plane.

**Recommendation 5:** AVIN is the power supply for the internal small-signal control circuits. It should be connected to the input voltage at a quiet point. In Figure 12 this connection is made with RAVIN at the input capacitor close to the \( V_{IN} \) connection.
Figure 123: EP53A7xQI Package PCB Footprint
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Figure 14: EP53A7xQI Package Dimensions